

VAM 120

120 Watts, 27 Volts, Class AB Defcom 100 - 150 MHz

GENERAL DESCRIPTION

The VAM 120 is a COMMON EMITTER device designed to operae in a collector modulated VHF power amplifier. It is a common emitter device, optimized for use in the 100-150 MHz range.

ABSOLUTE MAXIMUM RATINGS

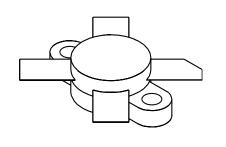
Maximum Power Dissipation @ 25°C 140 Watts

Maximum Voltage and Current

BVces Collector to Emiter Voltage 60 Volts
BVebo Emitter to Base Voltage 4.0 Volts
Ic Collector Current 12 A

Maximum Temperatures

Storage Temperature $-65 \text{ to } +150^{\circ}\text{C}$ Operating Junction Temperature $+200^{\circ}\text{C}$ CASE OUTLINE 55HT, Style 2



ELECTRICAL CHARACTERISTICS @ 25 °C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Pout	Power Output	F = 150 MHz	120			Watts
Pin	Power Input	Vcc = 27 Volts		15	20	Watts
Pg	Power Gain		7.8	9.0		dB
Pout		F = 150 MHz	30			Watts
Pin		Vcc = 13.5 Volts		7.5	10	Watts
Pg			4.8	6.0		dB
ης	Efficiency			65		%
VSWR	Load Mismatch Tolerance				30:1	

BVebo BVces BVceo Cob h _{FE}	Emitter to Base Breakdown Collector to Emitter Breakdown Collector to Emitter Breakdown Output Capacitance DC - Current Gain	Ie = 5 mA Ic = 20 mA Ie = 50 mA Vce = 5 V, Ic = 1 A	4.0 60 32	240		Volts Volts Volts pF
θjc	Thermal Resistance		- 0		1.2	°C/W

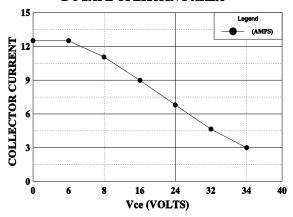
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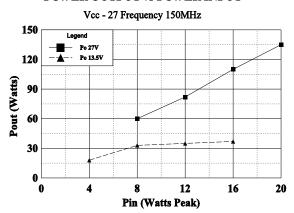
VAM -120



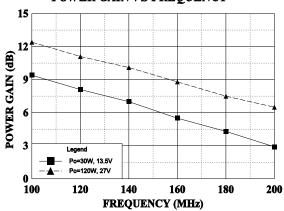
DC SAFE OPERATING AREA



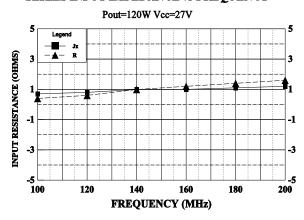
POWER OUTPUT vs POWER INPUT



POWER GAIN VS FREQUENCY



SERIES INPUT IMPEDANCE vs FREQUENCY



SERIES LOAD IMPEDANCE vs FREQUENCY

